

LISTING OF CLAIMS

The list of claims provided below replaces all prior versions and lists of claims in the application. Thus, claims 1-23 are pending.

Please amend the claims as follows.

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1. (Currently Amended) An apparatus for managing plasma in wafer processing operations, comprising:

10 a housing having an fluid entry port and a fluid exit port, the housing having an internal region defined by a top horizontal wall, a bottom horizontal wall and a circular side wall;

15 a plurality of baffle plates, each one of the plurality of baffle plates define a level in a multilevel structure formed in the internal region within the housing, each baffle plate being either separated from one another, or separated from either the top horizontal wall or the bottom horizontal wall by a separation spacing, each of the plurality of baffle plates including,

20 a plurality of holes, the plurality of holes in each of the baffle plates being oriented so that holes defined in each of the plurality of baffle plates are misaligned, thus defining a nonlinear path for fluids designed to enter the entry port, traverse each level of the multilevel structure defined by the plurality of baffle plates, the fluids capable of mixing together at each level of the multilevel structure, and leave the exit port of the housing; and

a gas inlet port in at least one of the separating spacing, the gas inlet port configured to inject gas into the housing in at least one of the separation spacing.

2. (Original) An apparatus for managing plasma in wafer processing operations as recited in claim 1, wherein the gas inlet port is in an uppermost separation spacing.

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3. (Original) An apparatus for managing plasma in wafer processing operations as recited in claim 1, wherein the gas inlet port is in a lowermost separation spacing.

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4. (Original) An apparatus for managing plasma in wafer processing operations as recited in claim 1, wherein gas injected from the gas inlet port mixes with the plasma in the separation spacing.

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5. (Original) An apparatus for managing plasma in wafer processing operations as recited in claim 1, wherein the plasma and the gas flowing through the nonlinear path within the housing undergoes turbulence and mixes.

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6. (Original) An apparatus for managing plasma in wafer processing operations as recited in claim 1, wherein the nonlinear path is designed to cause recombination in fluid gas traversing through the housing.

7. (Original) An apparatus for managing plasma in wafer processing operations as recited in claim 1, wherein each one of the plurality of baffle plates is circular.

5 8. (Original) An apparatus for managing plasma in wafer processing operations as recited in claim 1, wherein each one of the plurality of baffle plates is oriented horizontally in the housing.

9. (Original) An apparatus for managing plasma in wafer processing
10 operations as recited in claim 1, wherein the plurality of baffle plates includes 3 baffle plates.

10. (Previously Amended) An apparatus for managing plasma in wafer
processing operations as recited in claim 1, wherein each of the plurality of baffle plates
15 provide a baffle surface area causing an increased impedance.

11. (Original) An apparatus for managing plasma in wafer processing operations as recited in claim 1, wherein the plasma is a downstream plasma.

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12. (Currently Amended) An apparatus for optimizing plasma

delivery in wafer processing operations comprising:

a housing configured to have a first chamber and a second chamber, the first chamber and the second chamber being separated by a wall having a plurality of orifices, the housing having an input port at a first end for supplying a plasma into the first chamber and an output port at a second end of the housing, the input port and the output port being aligned with each other, but misaligned with each of the plurality of orifices; and

at least one fluid input, the at least one fluid input being configured to supply fluid into at least one of the first chamber and the second chamber, the plasma supplied through the input port ~~capable of being mixed with the supplied fluid within the at least one of the first chamber and the second chamber,~~ the first chamber and the second chamber each capable of simultaneously mixing the fluid and the plasma;

wherein the output port at the second end enables the supplied plasma mixed with the fluid supply to exit the second chamber.

13. (Original) An apparatus for optimizing plasma delivery in wafer processing operations as recited in claim 12, wherein the at least one fluid input is configured to supply fluid into the first chamber.

14. (Original) An apparatus for optimizing plasma delivery in wafer processing operations as recited in claim 12, wherein the at least one fluid input is configured to supply fluid into the second chamber.

15. (Original) An apparatus for optimizing plasma delivery in wafer processing operations as recited in claim 12, wherein a first fluid inlet is configured to supply fluid into the first chamber and a second fluid inlet is configured to supply fluid
5 into the second chamber.

16. (Original) An apparatus for optimizing plasma delivery in wafer processing operations as recited in claim 15, wherein the first fluid inlet and the second fluid inlet are managed separately and may inject fluid individually or in combination.
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17. (Original) An apparatus for optimizing plasma delivery in wafer processing operations as recited in claim 12, wherein the plasma is a downstream plasma.

18. (Currently Amended) An apparatus for managing plasma in wafer processing operations comprising:

a housing configured to have an internal region that is defined by an inner wall, the housing having an input port for supplying a plasma into the housing at a first end and an
5 output port at a second end;

a hollow tube, the hollow tube being contained in the internal region within the housing, the hollow tube having a top and a bottom, the top connected to the first end and the bottom connected to the second end and further being defined by a wall that extends between the first end and the second end, the hollow tube containing a plurality of orifices
10 that define a plurality of fluid paths through the wall; and

a fluid input, the fluid input being configured to supply fluid into the internal region of the housing, the supplied fluid capable of passing through the plurality of orifices in the wall of the hollow tube, the plasma supplied through the input port capable of being mixed within the hollow tube with the supplied fluid that enters the hollow tube
15 through the plurality of orifices;

wherein the output port at the second end of the housing enables the mixed plasma and fluid supply to exit the housing.

19. (Original) An apparatus for managing plasma in wafer processing
20 operations as recited in claim 18, further comprising:

a plasma generating source connected to the input port, the plasma generating source configured to produce the plasma.

20. (Original) An apparatus for managing plasma in wafer processing operations as recited in claim 18, further comprising:

a wafer processing chamber connected to the output port, the wafer processing chamber being configured to receive the mixed plasma from the output.

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21. (Original) An apparatus for managing plasma in wafer processing operations as recited in claim 18, wherein turbulence is created inside the hollow tube through receipt of the supplied fluid through the plurality of orifices.

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22. (Original) An apparatus for managing plasma in wafer processing operations as recited in claim 21, wherein the turbulence ensures mixing of the supplied fluid and the plasma.

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23. (Original) An apparatus for managing plasma in wafer processing operations as recited in claim 18, wherein the plasma is a downstream plasma.